Revision History

Revision 0.1 (Apr. 2006)

- First release.

Revision 0.2 (Feb. 2008).. - Modify ordering infomation.(page 2)

Revision 0.3 (Apr. 2008)..

- Update currently version "not supported burst mode" information.
- Modify Typical Performance Characteristics without burst mode (page 5)

2-CH, 600mA Synchronous Step-down Converter

DESCRIPTION

The EP3003 is a dual channel, 1.5MHz constant frequency, slope compensated current mode PWM step-down converter. The EP3003 can supply 600mA of load current from a 2.5V to 5.5V input voltage. Each output voltage is adjustable from 0.6V to 5V. It is ideal for powering portable equipment that runs from a single cell lithium-lon (Li+) battery. Internal synchronous 0.35Ω, 1A power switches provide high efficiency without the need for external Schottky diodes. The EP3003 can also run at 100% duty cycle for low dropout operation, extending battery life in portable system. Pulse Skipping Mode operation at light loads provides very low output ripple voltage for noise sensitive applications.

APPLICATIONS

- · Cellular and Smart Phones
- · Microprocessors and DSP Core Supplies
- · Wireless and DSL Modems
- PDAs
- · Portable Instruments / Media Players
- Digital Cameras

VIN = 2.5V to 5.5V

· PC Cards

VOUT2 = 2.5V

AT 600mA

C3

10uF

Typical Application

⊥cı

-10u

L2

C5, 22pF

Ř4

330k

2.2uH

_R3}

100k

FEATURES

- · High Efficiency: Up to 96%
- 1.5MHz Constant Switching Frequency
- 600mA Output Current
- Integrated Main Switch and Synchronous Rectifier
- · High Switch Current: 1A on Each Channel
- 2.5V to 5.5V Input Voltage Range
- Output Voltage as Low as 0.6V
- · 100% Duty Cycle in Dropout
- Low Quiescent Current: 50µA
- · Slope Compensated Current Mode Control for Excellent Line and Load Transient Response
- · Can be synchronized to an external oscillator
- Short Circuit Protection
- · Power-on Reset Output
- · Thermal Fault Protection
- <1uA Shutdown Current
- · Small Thermally Enhanced 10-Pin MSOP and 3mm × 3mm DFN Packages



Figure 1. Basic Application Circuit for 2.5V and 1.8V Output Voltages

C2

-10uF

R5 ξ

L1

2.2uH

100k

RESET

C4, 22pF

R2

R1 R2 150k 300k

RUN2 VIN RUN1

EP3003

GND

PO

SW

VEE

MODE/SYNC

M/2

Package/Order Information

MSOP:

DFN:



Ordering Information



Absolute Maximum Rating (Note1)

Input Supply Voltage0.3V to +6V
RUN, V _{FB} Voltages0.3V to VIN+0.3V
SW Voltages0.3V to VIN+0.3V
MODE/SYNC Voltages0.3V to VIN+0.3V
/POR Voltages0.3V to +6V
P-Channel Switch Source Current (DC)800mA
N-Channel Switch Sink Current (DC)800mA
Operating Temperature Range40°C to +85°C
Junction Temperature+125°C
Storage Temperature Range (MSOP) -65°C to +150°C
Storage Temperature Range (DFN)65°C to +125°C
Lead Temperature (Soldering, 10s)+300°C

Note 1. Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

Electrical Characteristics (Note 2) :

(V_{IN} =V_{RUN}= 3.6V, T_A = 25°C, unless otherwise noted.)

Parameter	Conditions	MIN	TYP	MAX	unit
Input Voltage Range		2.5		5.5	V
Input DC Supply Current					
Active Mode	V _{FB} =0.5V		600	800	μA
Shutdown Mode	RUN=0V, V _{IN} =5.5V, MODE/SYNC=0V		0.1	1.0	μA
Regulated Feedback	T _A = +25°C	0.588	0.600	0.612	V
Voltage	T_A = 0°C $\leq T_A \leq 85$ °C	0.586	0.600	0.613	V
	$T_{A}\text{=}\ \text{-}40^{\circ}C \ \leq \ T_{A} \ \leq \ 85^{\circ}C$	0.582	0.600	0.618	V
V _{FB} Input Bias Current				30	nA
Reference Voltage	V _{IN} = 2.5V to 5.5V		0.3	0.5	%/V
Line Regulation					
Power-On Reset	Threshold:				
(POR)	V _{FBX} Ramping Up, MODE/SYNC = 0V		8.5		%
	V _{FBX} Ramping Down, MODE/SYNC =		-8.5		%
	0V				
	Power-On Reset On-Resistance		100	200	Ω
	Power-On Reset Delay		270K		Cycles
Output Voltage Load			0.5		%
Regulation					
Peak Inductor Current	V _{IN} =3V, V _{FB} =0.5V	0.75	1.00	1.25	А
	Duty Cycle < 35%				
Oscillator Frequency	V _{FBX} =0.6V	1.2	1.5	1.8	MHz
Synchronization			1.5		MHz
Frequency					
R _{DS(ON)}	Top Switch On-Resistance		0.35	0.45	Ω
	Bottom Switch On-Resistance		0.30	0.45	Ω
SW Leakage	V _{RUN} = 0V, V _{FBX} = 0V,		0.01	1	μA
	V _{IN} = 5V				
RUN Threshold	-40°C \leq T _A \leq 85°C	0.3	1.0	1.50	V
RUN Leakage Current			±0.01	±1	μA

Note 2. 100% production test at +25°C. Specifications over the temperature range are guaranteed by design and characterization.

Typical Performance Characteristics (TBD)



Functional Block Diagram



Pin Description

PIN	NAME	FUNCTION				
1	V _{FB1}	Output Voltage Feedback Pin. An internal resistive divider divides the output voltage				
		down for comparison to the internal reference voltage. Nominal voltage for this pin is				
		0.6V.				
2	RUN1	Regulator 1 Enable control input. Forcing this pin to VIN enables regulator 1, while				
		forcing it to GND causes regulator 1 to shut down. In shutdown, all functions are				
		disabled drawing <1µA supply current. Do not leave RUN floating.				
3	V _{IN}	Main Power Supply. Must be closely decoupled to GND with a ceramic capacitor.				
4	SW1	Regulator 1 Power Switch Output. Switch Node Connection to the				
		Inductor. This pin swings from VIN to GND.				
5	GND	Ground				
6	Mode/Sync	Combination of Mode Selection and Oscillator Synchronization. This pin controls the				
		operation of the device. When tied to V_{IN} or GND, Burst Mode operation or pulse				
		skipping mode is selected, respectively. Do not float this pin. The oscillation frequency				
		can be synchronized to an external oscillator applied to this pin and pulse skipping mode				
		is automatically selected. (Current version "Burst Mode" is not supported)				
7	SW2	Regulator 2 Power Switch Output. Switch Node Connection to the Inductor. This pin				
		swings from V _{IN} to GND.				
8	/POR	Power-On Reset. This common-drain logic output is pulled to GND when the output				
		voltage is not within $\pm 8.5\%$ of regulation and goes high after 175ms when both channels				
		are within regulation.				
9	RUN2	Regulator 2 Enable control input. Forcing this pin to V_{IN} enables regulator 2, while				
		forcing it to GND causes regulator 2 to shut down.				
10	V _{FB2}	Output Voltage Feedback Pin for Regulator 2. See V _{FB1} section.				
11	Power	Connect to the (-) terminal of COUT, and (-) terminal of CIN. Must be soldered to				
	Ground	electrical ground on PCB.				

OPERATION

The EP3003 uses current mode architecture with frequency set at 1.5MHz and can be synchronized to an external oscillator. Both channels share the same clock and run in-phase. To suit a variety of applications, the selectable Mode pin allows the user to trade-off noise for efficiency.

Output voltage is set by an external divider returned to the VFB pins. An error amplifier compares the divided output voltage with a reference voltage of 0.6V and adjusts the peak inductor current accordingly. Over voltage and under voltage comparators will pull the POR output low if the output voltage is not within ±8.5%. The POR output will go high after 270K clock cycles of achieving regulation. During normal operation, the top power switch (P-channel MOSFET) is turned on at the beginning of a clock cycle when the VFB voltage is below the reference voltage.

The current into the inductor and the load increases until the current limit is reached. The switch turns off and energy stored in the inductor flows through the bottom switch (N-channel MOSFET) into the load until the next clock cycle.

The peak inductor current is controlled by the internally compensated ITH voltage, which is the output of the error amplifier. This amplifier compares the VFB pin to the 0.6V reference. When the load current increases, the V_{FB} voltage decreases slightly below the reference. This decrease causes the error amplifier to increase the ITH voltage until the average inductor current matches the new load current. The main control loop is shut down by pulling the RUN pin to ground.

Low Current Control

Pulse skipping mode is available to control the operation of the EP3003 at low currents.

For lower ripple noise at low currents, the pulse skipping mode can be used. In this mode, the EP3003 continues to switch at a constant frequency down to very low currents, where it will begin skipping pulses.

Dropout Operation

The EP3003 allows the main switch to remain on for more than one switching cycle and increases the duty cycle until it reaches 100%. The output voltage then is the input voltage minus the voltage drop across the main switch and the inductor. At low input supply voltage, the R_{DS(ON)} of the P Channel MOSFET increases, and the efficiency of the converter decreases. Caution must be exercised to ensure the heat dissipated not to exceed the maximum junction temperature of the IC.

Note 3. The duty cycle D of a step-down converter is defined as:

 $\mathsf{D} = \mathsf{T}_{\mathsf{ON}} \ x \ \mathsf{f}_{\mathsf{OSC}} \ x \ \mathsf{100\%} \approx \mathsf{V}_{\mathsf{OUT}}/\mathsf{V}_{\mathsf{IN}} \ x \ \mathsf{100\%}$

where T_{ON} is the main switch on time, and f_{OSC} is the oscillator frequency (1.5MHz).

Maximum Load Current

The EP3003 will operate with input supply voltage as low as 2.5V, however, the maximum load current decreases at lower input due to large IR drop on the main switch and synchronous rectifier. The slope compensation signal reduces the peak inductor current as a function of the duty cycle to prevent sub-harmonic oscillations at duty cycles greater than 50%. Conversely the current limit increases as the duty cycle decreases.

APPLICATIONS INFORMATION

A general application circuit for EP3003 is shown in Figure 1, which is the baseline for some calculation mentioned below. All external component selection for EP3003 application design will be illustrated as the following.

Setting the Output Voltage

The external resistor sets the output voltage according to the following equation:

$$V_{out} = 0.6V \left(1 + \frac{R2}{R1}\right)$$

R1 = $150K\Omega$; R2 = $300K\Omega$ for V_{OUT} = 1.8V;

R3 = 100K Ω ; R4 = 330K Ω for V_{OUT} = 2.5V.

Inductor Selection

For most designs, the EP3003 operates with inductors of 1µH to 4.7µH. Low inductance values are physically smaller but require faster switching, which results in some efficiency loss. Large value inductors lower ripple current and small value inductors result in high ripple currents. The inductor value can be derived from the following equation:

$$L = \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{V_{IN} \times \Delta I_L \times f_{OSC}}$$

where ΔI_L is inductor Ripple Current. Choose inductor ripple current approximately 35% of the maximum load current 600mA, or 210mA.

For output voltages above 2.0V, when light-load efficiency is important, the minimum recommended inductor is 2.2 μ H. For optimum voltage-positioning load transients, choose an inductor with DC series resistance in the 50m Ω to 150m Ω range. For higher efficiency at heavy loads (above 200mA), or minimal load regulation (but some transient overshoot), the resistance should be kept below 100m Ω . The DC current rating of the inductor should be at least equal to the maximum load current plus half the ripple current to prevent core saturation (600mA+105mA). Table 1 lists some typical surface mount inductors that meet target applications for the EP3003.

	1				
Part #	L (µH)	Max DCR (m.)	Rated D.C. Current (A)	Size WxLxH (mm)	
Sumida	1.4	56.2	2.52		
CR43	2.2	71.2	1.75	4.5x4.0x3.5	
	3.3	86.2	1.44		
	4.7	108.7	1.15		
Sumida	1.5				
CDRH4D18	2.2	75	1.32	4.7x4.7x2.0	
	3.3	110	1.04		
	4.7	162	0.84		
Toko	1.5	120	1.29		
D312C	2.2	140	1.14	3.6x3.6x1.2	
	3.3	180	0.98		
	4.7	240	0.79		

Input Capacitor Selection

The input capacitor reduces the surge current drawn from the input and switching noise from the device. The input capacitor impedance at the switching frequency shall be less than input source impedance to prevent high frequency switching current passing to the input. A low ESR input capacitor sized for maximum RMS current must be used. Ceramic capacitors with X5R or X7R dielectrics are highly recommended because of their low ESR and small temperature coefficients. A 10µF ceramic capacitor for most applications is sufficient.

Output Capacitor Selection

The output capacitor is required to keep the output voltage ripple small and to ensure regulation loop stability. The output capacitor must have low impedance at the switching frequency. Ceramic capacitors with X5R or X7R dielectrics are recommended due to their low ESR and minimization of large temperature and voltage coefficients. The output ripple ΔV_{OUT} is determined by:

$$\Delta V_{OUT} \leq \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{V_{IN} \times f_{OSC} \times L} \times \left(ESR + \frac{1}{8 \times f_{OSC} \times C3} \right)$$

Package Description DFN:



MSOP:



